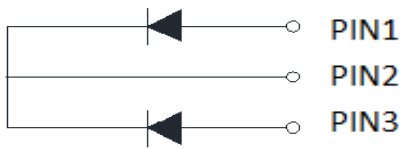
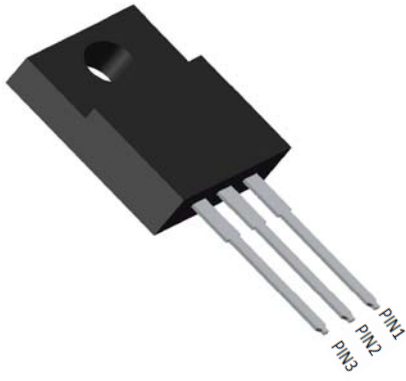


## Schottky Diodes



### Features

- High frequency operation
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Solder dip 275 °C max. 7 s, per JESD 22-B106

### Typical Applications

Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

### Mechanical Data

- **Package:** ITO-220AB  
Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant
- **Terminals:** Tin plated leads, solderable per J-STD-002 and JESD22-B102
- **Polarity:** As marked

### ■Maximum Ratings (T<sub>a</sub>=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	MBR10100FCTS	MBR10150FCTS	MBR10200FCTS
Device marking code			MBR10100FCTS	MBR10150FCTS	MBR10200FCTS
Repetitive Peak Reverse Voltage	V <sub>RRM</sub>	V	100	150	200
Average Rectified Output Current @60Hz sine wave, R-load, T <sub>c</sub> =140°C	I <sub>o</sub>	A	10		
Surge(Non-repetitive)Forward Current @60Hz half sine-wave, 1 cycle, T <sub>a</sub> =25°C	I <sub>FSM</sub>	A	100		
Current Squared Time @1ms≤t≤8.3ms T <sub>j</sub> =25°C,	I <sup>2</sup> t	A <sup>2</sup> s	41		
Storage Temperature	T <sub>stg</sub>	°C	-55 ~ +175		
Junction Temperature	T <sub>j</sub>	°C	-55 ~ +175		

### ■Electrical Characteristics (T<sub>a</sub>=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	MBR10100FCTS	MBR10150FCTS	MBR10200FCTS
Maximum instantaneous forward voltage drop per diode	V <sub>FM</sub>	V	I <sub>FM</sub> =5.0A	0.85	0.9	0.95
Maximum DC reverse current at rated DC blocking voltage per diode	I <sub>RRM1</sub>	mA	V <sub>RM</sub> =V <sub>RRM</sub> T <sub>a</sub> =25°C	0.1		
	I <sub>RRM2</sub>		V <sub>RM</sub> =V <sub>RRM</sub> T <sub>a</sub> =125°C	20		

### ■Thermal Characteristics (T<sub>a</sub>=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	MBR10100FCTS	MBR10150FCTS	MBR10200FCTS
Thermal Resistance Between junction and case	R <sub>θJ-C</sub>	°C/W	4.0		



# MBR10100FCTS THRU MBR10200FCTS

## Ordering Information (Example)

PREFERED P/N	UNIT WEIGHT(g)	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
MBR10100FCTS THRU MBR10200FCTS	Approximate 1.9	50	1000	5000	Tube

## Characteristics (Typical)

FIG1:Io -Tc Curve

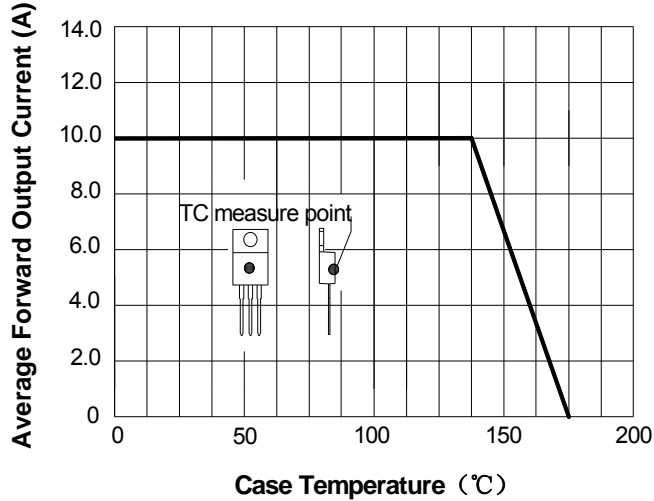


FIG2: Surge Forward Current Capability

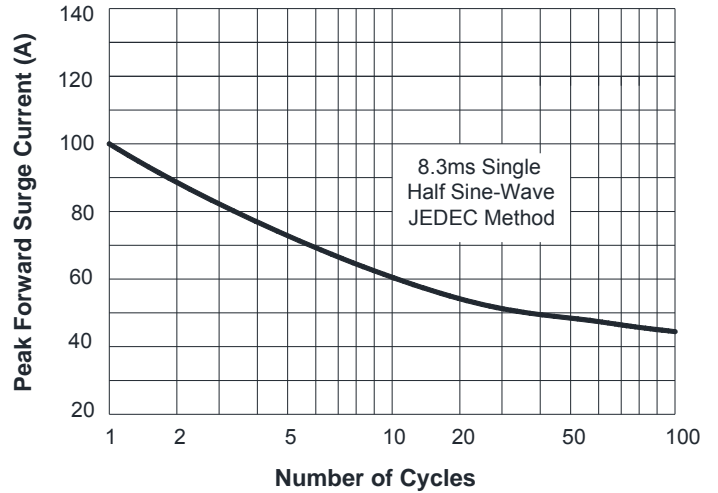


FIG3: Forward Voltage

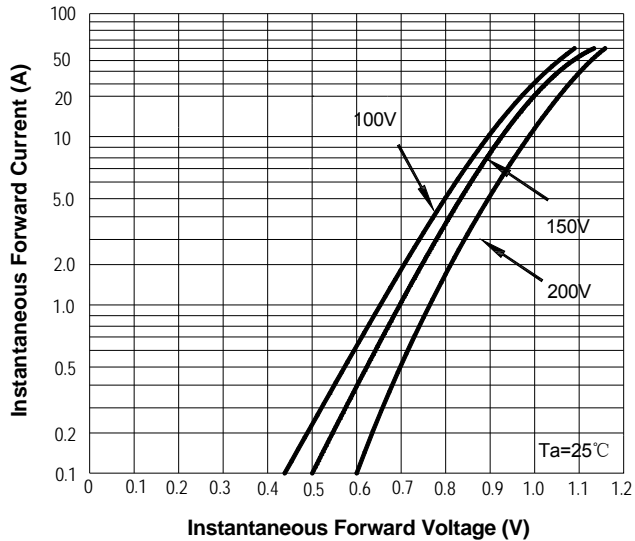
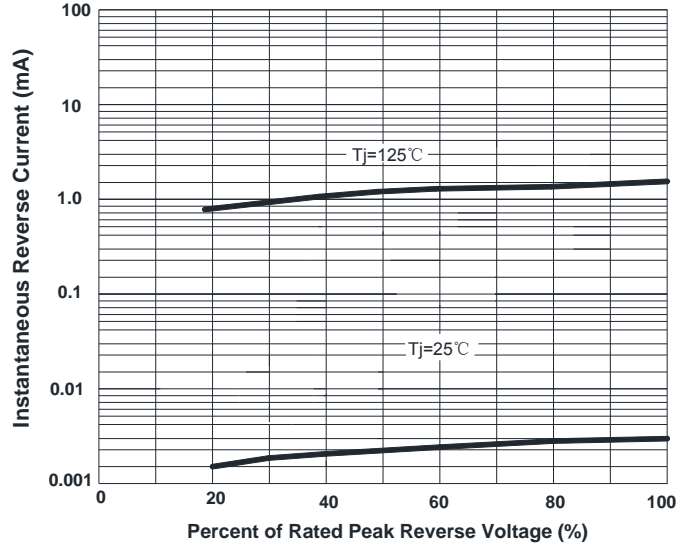


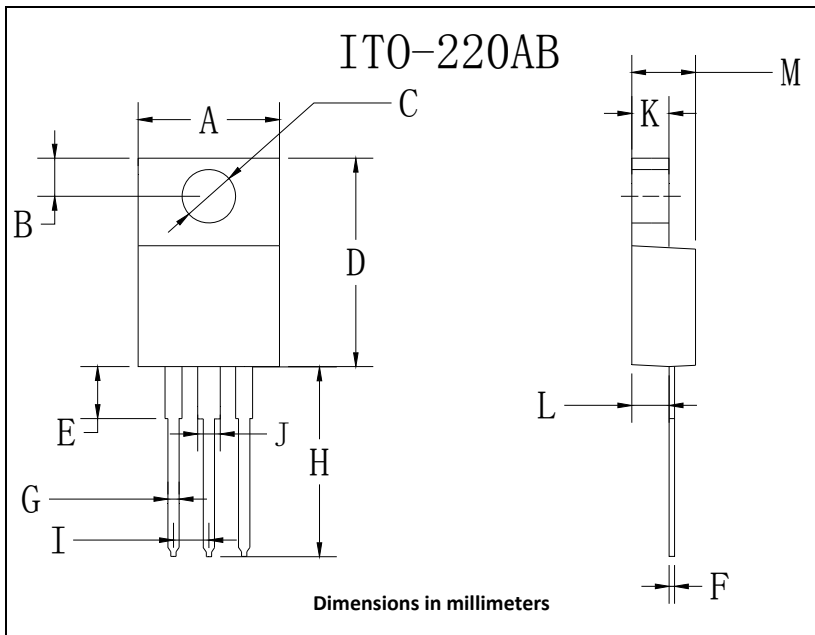
FIG4: Instantaneous Reverse Characteristics





# MBR10100FCTS THRU MBR10200FCTS

## ■Outline Dimensions



ITO-220AB		
Dim	Min	Max
A	9.7	10.7
B	2.15	3.25
C	2.6	3.8
D	14.4	15.9
E	3.1	4.5
F	0.4	0.8
G	0.4	0.8
H	12.7	14.2
I	1.80	2.95
J	1.4	1.8
K	2.1	3.56
L	2.1	3.2
M	3.9	5.1



## MBR10100FCTS THRU MBR10200FCTS

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